Dual P-Channel 1.8-V (G-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A)	Q _g (Тур)			
-20	0.110 @ $V_{GS} = -4.5 V$	-3.6				
	0.160 @ V _{GS} = -2.5 V	-3.0	5.1			
	$0.240 @ V_{GS} = -1.8 V$	-2.4				

FEATURES

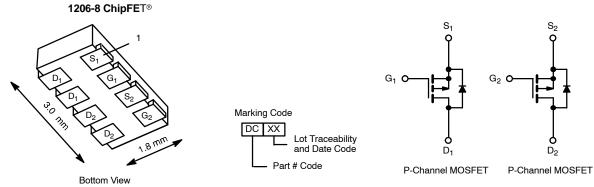
1.8-V Rated

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TrenchFET[®] Power MOSFET

Pb-free Available

Si5933DC



Ordering Information: Si5933DC-T1 Si5933DC-T1—E3 (Lead (Pb)-Free)

Parameter		Symbol	5 secs	Steady State	Unit
Drain-Source Voltage		V _{DS}	-20		V
Gate-Source Voltage		V _{GS}	±8		
	$T_A = 25^{\circ}C$	l _D	-3.6	-2.7	А
Continuous Drain Current $(T_J = 150^{\circ}C)^a$	T _A = 85°C		-2.6	-1.9	
Pulsed Drain Current		I _{DM}	-10		A
Continuous Source Current (Diode Conduction) ^a		I _S	-1.8	-0.9	
Maximum Power Dissipation ^a	$T_A = 25^{\circ}C$	- P _D	2.1	1.1	w
	T _A = 85°C		1.1	0.6	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150		°C
Soldering Recommendations (Peak Temperature) ^{b, c}			260		

THERMAL RESISTANCE RATINGS									
Parameter		Symbol	Typical	Maximum	Unit				
	$t \le 5 \sec$	R _{thJA}	50	60	°C/W				
Maximum Junction-to-Ambient ^a	Steady State		90	110					
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	30	40					

Notes

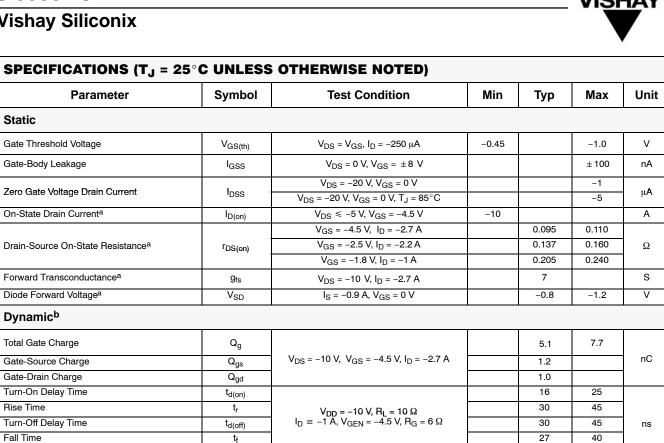
Surface Mounted on 1" x 1" FR4 Board. a.

See Reliability Manual for profile. The ChipFET is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconb. nection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.

Document Number: 71238 S-50366-Rev. D, 28-Feb-05 Static

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Notes

Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2%. a.

Source-Drain Reverse Recovery Time

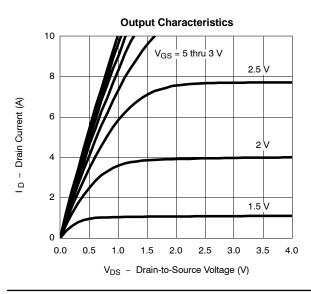
Guaranteed by design, not subject to production testing. b.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

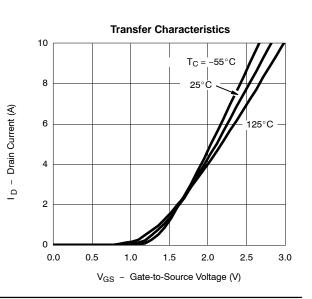
I_F = -0.9 A, di/dt = 100 A/µs

TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)

t_{rr}



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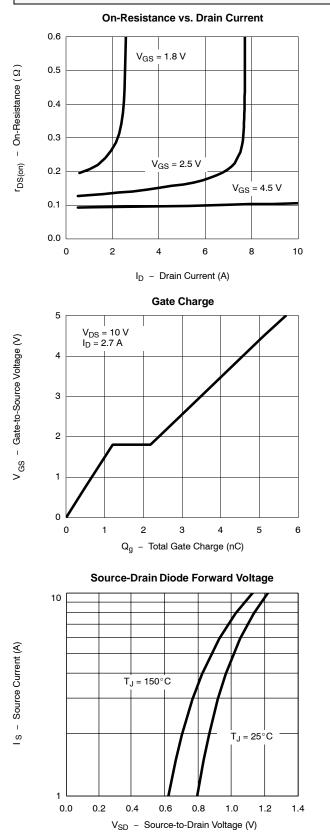
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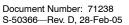
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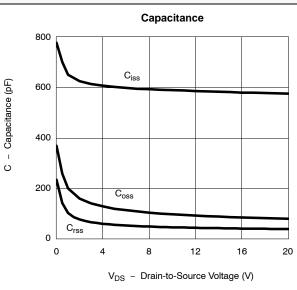


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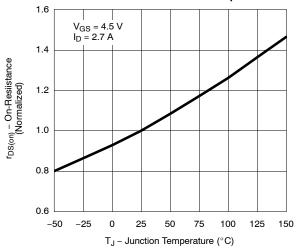
TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



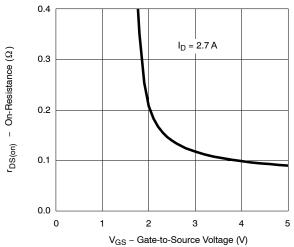




On-Resistance vs. Junction Temperature



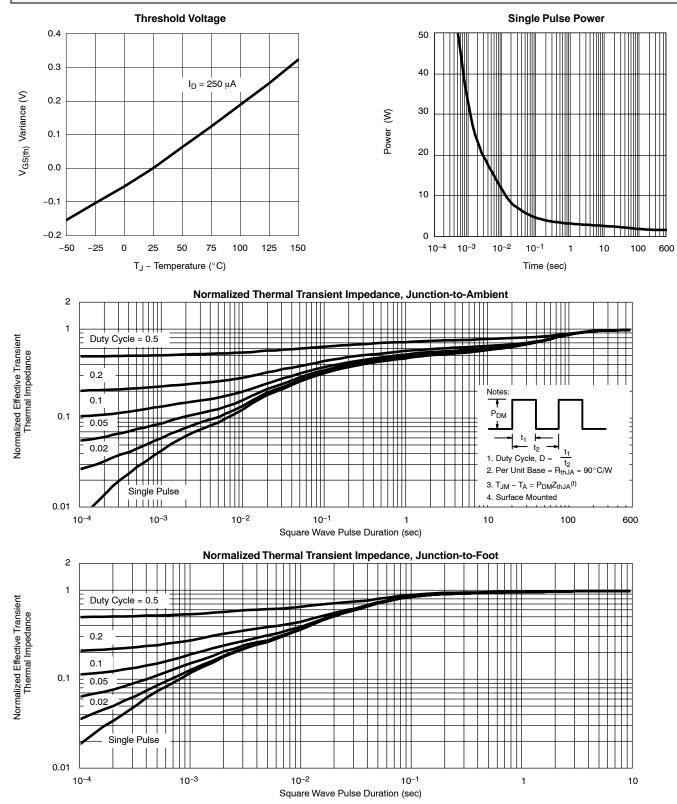
On-Resistance vs. Gate-to-Source Voltage



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TYPICAL CHARACTERISTICS (25°C UNLESS NOTED)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?71238.

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